

D2SB60L

600V 1.5A

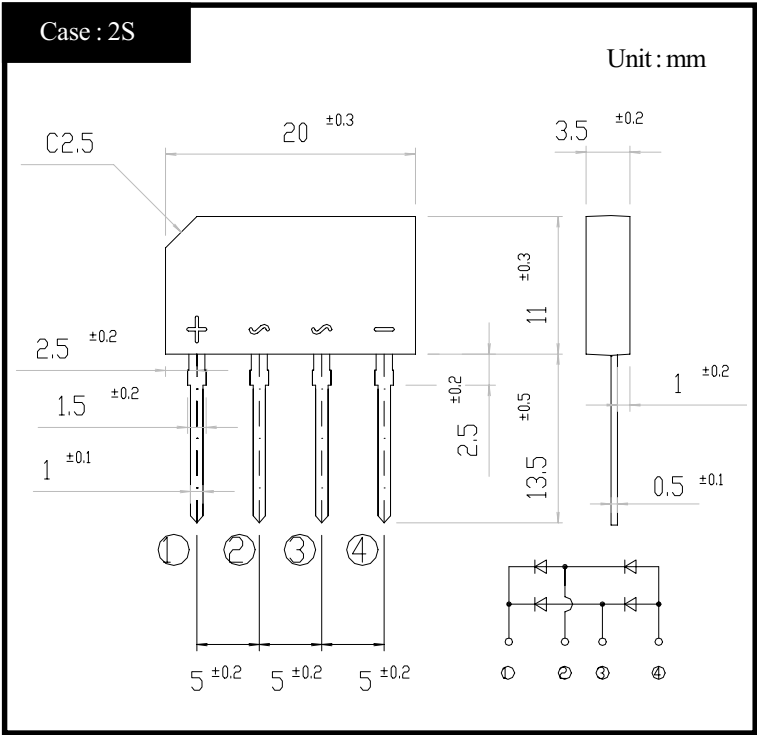
FEATURES

- Thin Single In-Line Package
- High IFSM
- Applicable to Automatic Insertion

APPLICATION

- Switching power supply
- Home Appliances, Office Equipment
- Telecommunication, Factory Automation

OUTLINE DIMENSIONS



RATINGS

- Absolute Maximum Ratings (If not specified Tl=25°C)

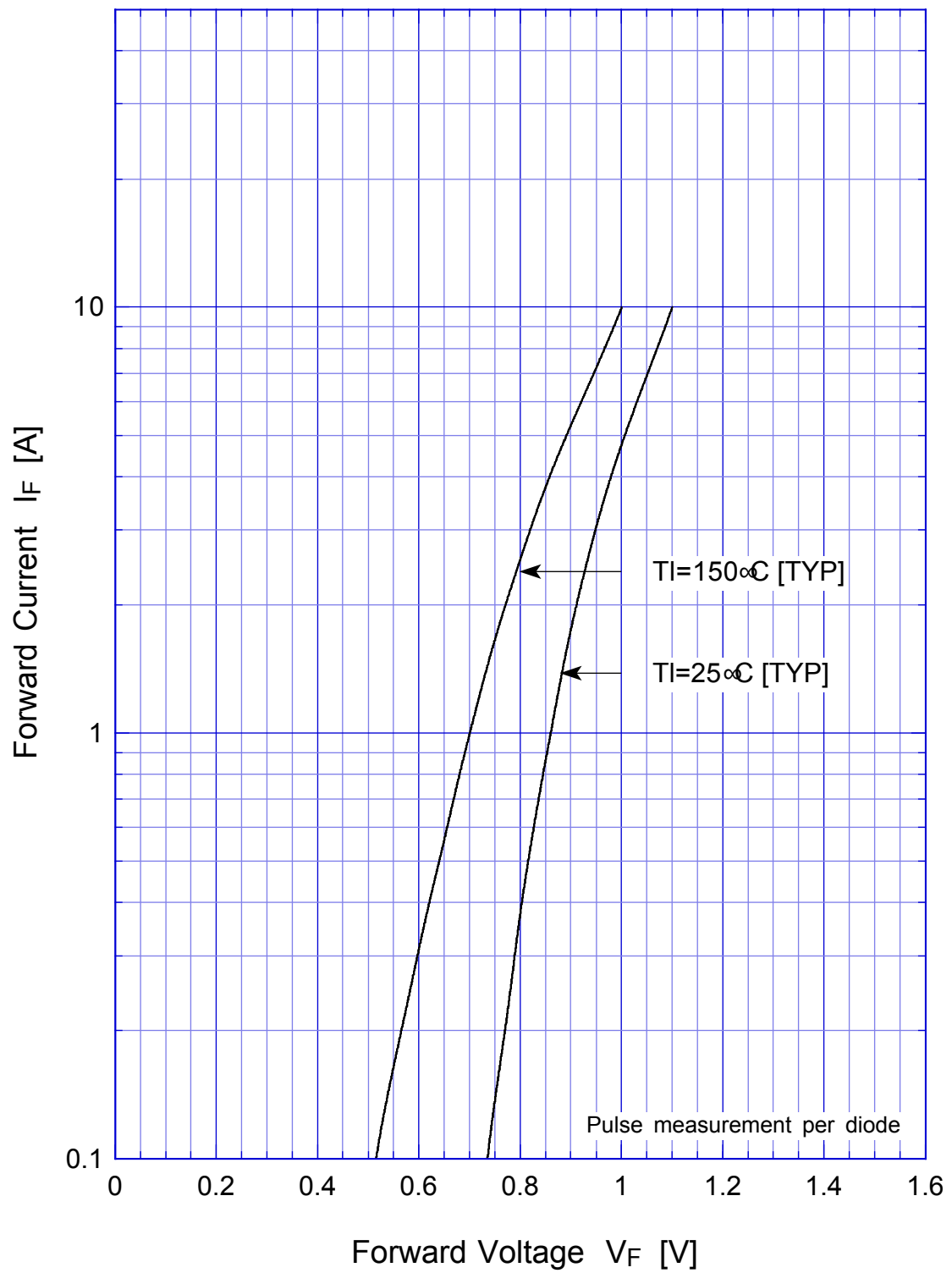
Item	Symbol	Conditions	Ratings	Unit
Storage Temperature	T _{stg}		-40~150	°C
Operating Junction Temperature	T _j		150	°C
Maximum Reverse Voltage	V _{RM}		600	V
Average Rectified Forward Current	I _O	50Hz sine wave, R-load, On glass-epoxy substrate, Ta=25°C	1.5	A
Peak Surge Forward Current	I _{FSM}	50Hz sine wave, Non-repetitive 1cycle peak value, Tj=25 °C	120	A
Current Squared Time	I ² t	1ms≤t<10ms Tj= 25°C	40	A ² s

- Electrical Characteristics (If not specified Tl=25°C)

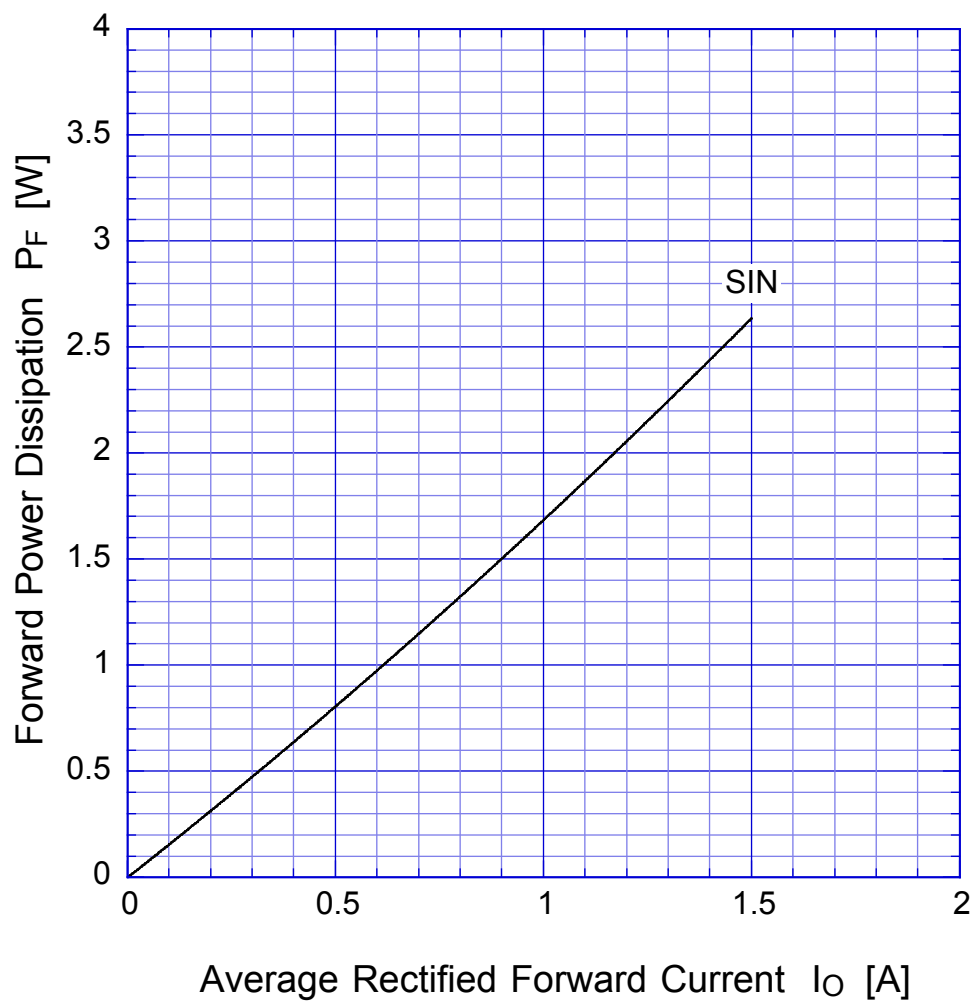
Item	Symbol	Conditions	Ratings	Unit
Forward Voltage	V _F	I _F =0.75A, Pulse measurement, Rating of per diode	Max.1.05	V
Reverse Current	I _R	V _R =V _{RM} , Pulse measurement, Rating of per diode	Max.10	μ A
Reverse Recovery Time	t _{rr}	I _F =0.1A, I _R =0.1A, Rating of per diode	Max.10	μ s
Thermal Resistance	θ _{jl}	junction to lead	Max.10	°C/W
	θ _{ja}	junction to ambient	Max.47	

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Forward Voltage



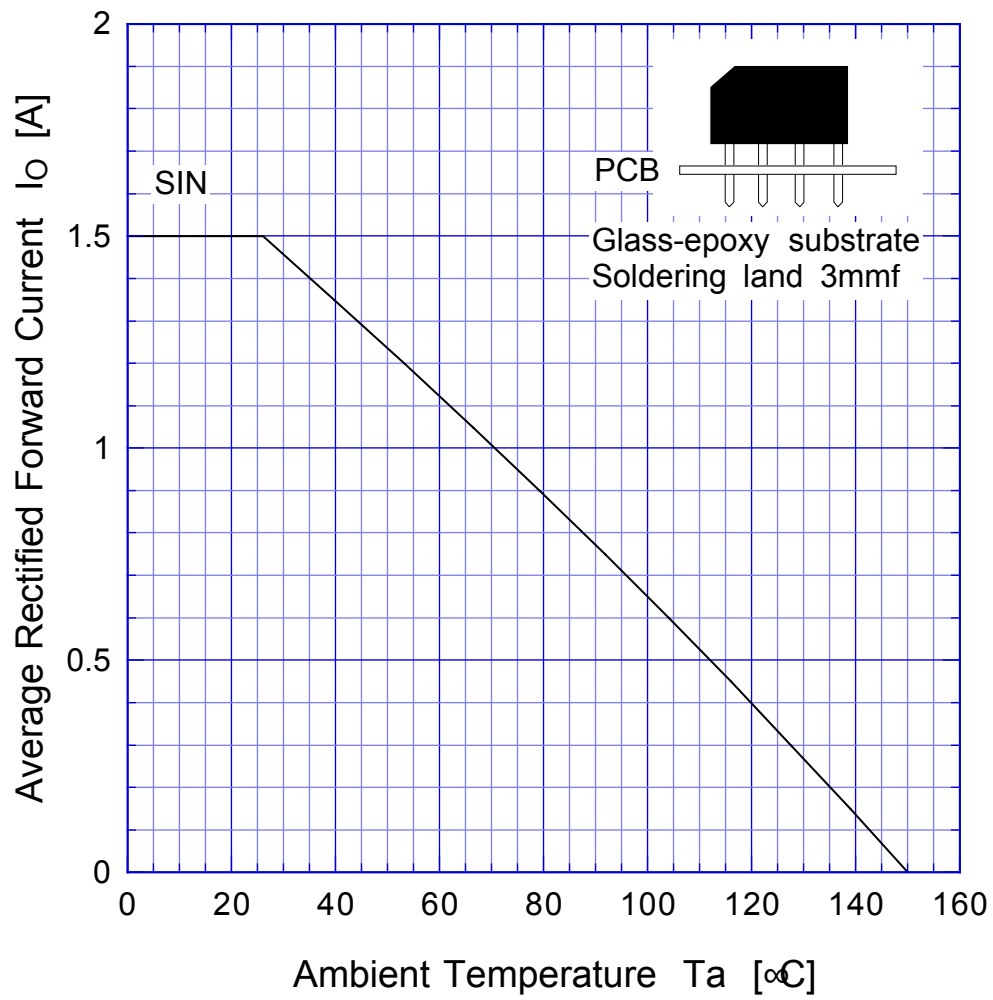
D2SB60L Forward Power Dissipation



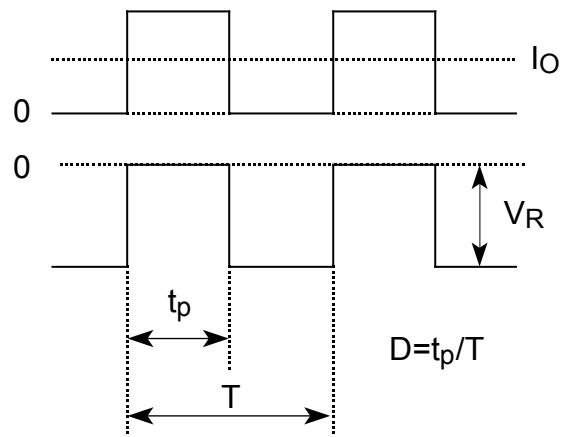
$T_j = 150^{\circ}\text{C}$
Sine wave

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Derating Curve



$V_R = 600V$



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Peak Surge Forward Capability

